

Low Temperature Cure LTC 9300(-E07)

Photosensitive Polyimide Precursor

- NMP / NEP and halogen free formulation.
- LTC 9300(-E07) series are suitable for low temperature cure between 200 and 250°C.
- Standard cure conditions between 350°C and 420°C can also be applied.
- LTC 9300(-E07) series are designed to provide the following characteristics:
 - · Copper compatible polyimide
 - · Wide process latitude
 - · Self priming no external adhesion promotor
 - · Very good adhesion
 - Good mechanical property retention after extended pressure cooker test (> 1000 hours)
- · Large cured film thickness ranges.

Туре	Viscosity*	Cured Film Thickness
LTC 9305	1200 cSt	2 – 5 µm
LTC 9310-E07	3300 cSt	4 – 15 μm
LTC 9320-E07	6100 cSt	8 – 25 µm
(* 1 cSt = 1 mm2/s)		

 Ideal for standardization purposes and minimizing the number of polyimide materials in production.

Compatible Ancillary Products:

Developer/Rinse Combinations: HTR-D2 / RER 600

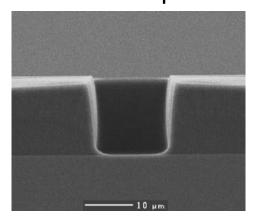
Back Side Rinse: HTR-D2 Edge Bead Remover: HTR-D2

Stripper Product: MS 3001 (NMP free)

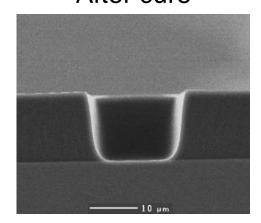
Typical cured Film Properties of LTC 9300(-E07)

Material property	Unit	Cured @ 230°C	Cured @ 350°C
Modulus	GPa	2.5	2.2
Elongation at break	%	83	> 85
Tensile strength	MPa	181	202
Tg	°C	229	237
CTE	ppm	55	53
Weight loss Temp (2%)	°C	309	382
Weight loss Temp (5%)	°C	340	409

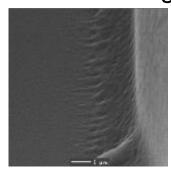
After development



After cure



Limited footing



Process Window

Substrate: All types

Silicon, SiO_xN_y , epoxy, Al, Cu, Ag,

Au,...

PI Thickness: 2 to 35+ μm Soft Bake: Depending film

> thickness range 100°C / 4-6 min

Exposure Tool: Mask aligner

Stepper BB or I-line

Exp. Range: 150-600 mJ/cm² **Focus Range:** 3-8 µm into PI film

Post Exposure Delay: 30 min @ RT

or

Post Exposure Bake: 60 sec @ 50°C

Dev. process: Atomized spray,

continuous spray or

multiple puddle development

Developer/Rinse: HTR-D2/RER 600

Final cure conditions:

1. Low temperature cure:

Cure temp: 200 to 240°C for 180 min

2. Medium temperature cure:

Cure temp: 250 to 300°C for 90 min

3. Standard temperature cure:

Cure temp: 350 to 420°C for 60 min

Descum:

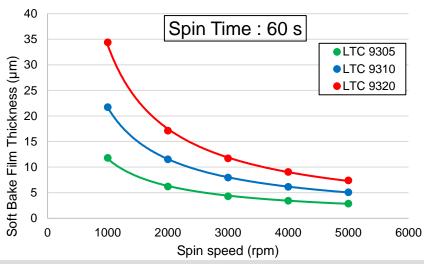
Short O₂-plasma

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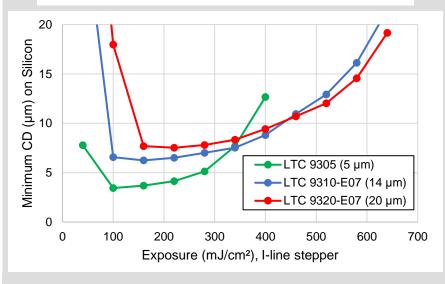
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Soft Bake Film Thickness vs. Spin Speed



Recommended spin time is 30-60 seconds. Film thickness can be varied by changing the spin-time and spin-speed.

Minimum Dimension vs. Exposure Dose



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